VS-VSKU71.., VS-VSKV71.. Series







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ADD-A-PAK

PRIMARY CHARACTERISTICS						
I _{T(AV)}	75 A					
Туре	Modules - thyristor, standard					
Package	AAP Gen 7 (TO-240AA)					

MECHANICAL DESCRIPTION

The AAP Gen 7 (TO-240AA), new generation of AAP module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- High voltage
- Industrial standard package
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{T(AV)}	85 °C	75					
I _{T(RMS)}		115	A				
I _{TSM}	50 Hz	1300	A				
	60 Hz	1360					
l ² t	50 Hz	8.45					
1-1	60 Hz	7.68	kA ² s				
l²√t		84.5	kA²√s				
V _{RRM}	Range	400 to 1600	V				
T _{Stg}		-40 to +125	°C				
TJ		-40 to +125	°C				



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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I _{RRM,} I _{DRM} AT 125 °C mA			
	04	400	500	400				
VS-VSK.71	08	800	900	800	15			
vo-von./1	12	1200	1300	1200	15			
	16	1600	1700	1600				

ON-STATE CONDUCTION						
PARAMETER	SYMBOL		VALUES	UNITS		
Maximum average on-state current	I _{T(AV)}	180° conductio	180° conduction, half sine wave, $T_C = 85 \ ^\circ C$			٨
Maximum continuous RMS on-state current	1	DC			115	A
Maximum continuous RMS on-state current	I _{T(RMS)}	T _C			80	°C
		t = 10 ms	No voltage		1300	
Maximum peak, one-cycle non-repetitive		t = 8.3 ms	reapplied	Sinusoidal	1360	٨
on-state current	I _{TSM}	t = 10 ms	100 % V _{RRM}	half wave, initial T _{-I} = T _{-I} maximum	1093	A
		t = 8.3 ms	reapplied		1140	
		t = 10 ms	No voltage		8.45	kA ² s
Maximum 12t for fusing	l ² t	t = 8.3 ms	reapplied		7.68	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}	Initial $T_J = T_J$ maximum	5.97	
		t = 8.3 ms	reapplied		5.45	
Maximum I ² \sqrt{t} for fusing	l ² √t ⁽¹⁾		t = 0.1 ms to 10 ms, no voltage reapplied T ₁ = T ₁ maximum			
	V _{T(TO)} ⁽²⁾	Low level (3)			0.96	
Maximum value of threshold voltage		High level ⁽⁴⁾	$T_J = T_J maxin$	num	1.08	V
Maximum value of on-state	. (2)	Low level (3)	T T D D		3.28	
slope resistance	r _t ⁽²⁾	High level (4)	$T_J = T_J maxin$	num	2.86	mΩ
Maximum on-state voltage drop	V _{TM}	$I_{TM} = \pi \times I_{T(AV)}$	T _J = 25 °C		1.72	V
Maximum non-repetitive rate of rise of turned on current	dl/dt	$T_J = 25 \text{ °C, from}$ $I_{TM} = \pi \times I_{T(AV)},$	150	A/µs		
Maximum holding current	I _H	T _J = 25 °C, and resistive load,	250	mA		
Maximum latching current	١L	$T_J = 25 \text{ °C}, \text{ and}$	ode supply = 6 \	/, resistive load	400	

Notes

⁽¹⁾ I²t for time $t_x = I^2 \sqrt{t} x \sqrt{t_x}$

⁽²⁾ Average power = $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$

⁽³⁾ 16.7 % x π x $I_{AV} < I < \pi$ x I_{AV}

⁽⁴⁾ $I > \pi \times I_{AV}$



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TRIGGERING					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}			12	W
Maximum average gate power	P _{G(AV)}			3.0	vv
Maximum peak gate current	I _{GM}			3.0	А
Maximum peak negative gate voltage	- V _{GM}			10	
	V _{GT}	T _J = - 40 °C	Anode supply = 6 V resistive load	4.0	V
Maximum gate voltage required to trigger		T _J = 25 °C		2.5	
		T _J = 125 °C		1.7	
	I _{GT}	T _J = - 40 °C		270	mA
Maximum gate current required to trigger		T _J = 25 °C	Anode supply = 6 V resistive load	150	
		T _J = 125 °C		80	
Maximum gate voltage that will not trigger	V _{GD}	T_J = 125 °C, rated V_{DRI}	0.25	V	
Maximum gate current that will not trigger	I _{GD}	$T_J = 125 \text{ °C}, \text{ rated } V_{DRM} \text{ applied} $ 6			mA

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak reverse and off-state leakage current at V _{RRM} , V _{DRM}	I _{RRM,} I _{DRM}	T _J = 125 °C, gate open circuit	15	mA				
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = 125 \text{ °C}$, linear to 0.67 V_{DRM}	1000	V/µs				

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Junction operating and storage temperature range		T _J , T _{Stg}		-40 to +125	°C		
Maximum internal thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.29	°C/W		
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.1	C/W		
Mounting torgue ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm		
	busbar		3 hours to allow for the spread of the compound.	3	INITI		
Approximate weight				75	g		
				2.7	OZ.		
Case style			JEDEC®	AAP Gen 7	(TO-240AA)		

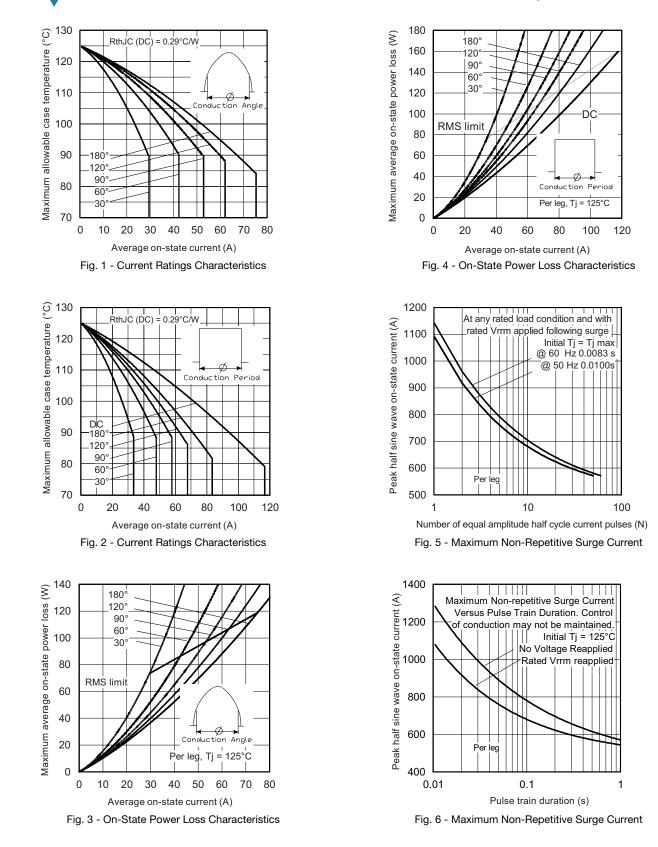
DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.71	0.052	0.062	0.079	0.116	0.197	0.037	0.064	0.085	0.121	0.200	°C/W

Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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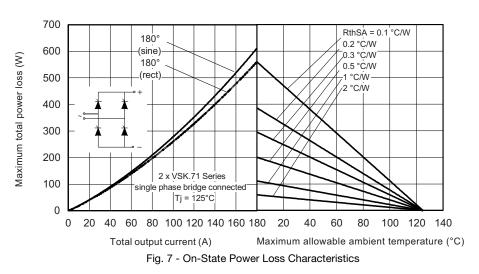
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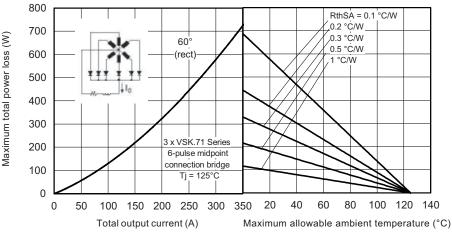
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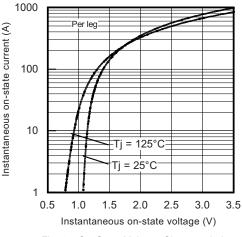
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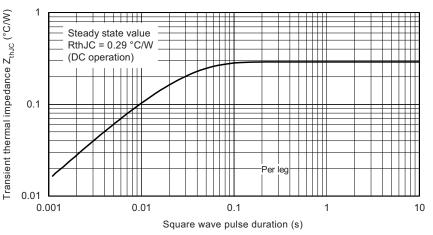


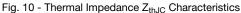


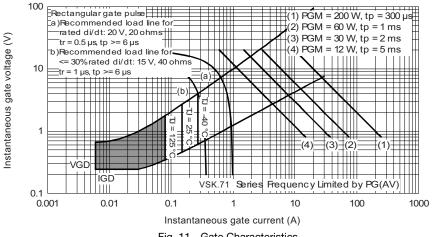


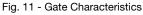






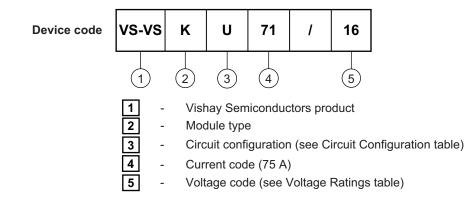






ORDERING INFORMATION TABLE

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Note

To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

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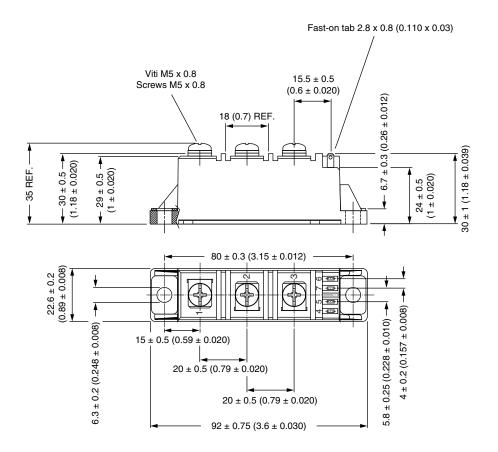
CIRCUIT CONFIGURATION	CIRCUIT CONFIGURATION								
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CO	DE CIRCUIT DRAWING							
Two SCRs common cathodes	U	VSKU 1 2 (1) (1) (1) (2) (2) (2) (2) (3) (3) (3) (3) (3) (4) (5) (7) (6)							
Two SCRs common anodes	V	VSKV (1) (1) (2) (2) (2) (2) (2) (3) (3) (3) (3) (3) (4) (5) (7) (6)							
	LINKS TO RELATE	D DOCUMENTS							
Dimensions		www.vishay.com/doc?95368							

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ADD-A-PAK Generation VII - Thyristor

DIMENSIONS in millimeters (inches)

SHA





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